NSN 5961-00-009-8093

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-009-8093 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No